To our customers,

Old Company Name in Catalogs and Other Documents

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April 1st, 2010
Renesas Electronics Corporation

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RENESAS

MOS FIELD EFFECT TRANSISTOR

μPA1717

SWITCHING
P-CHANNEL POWER MOS FET
INDUSTRIAL USE

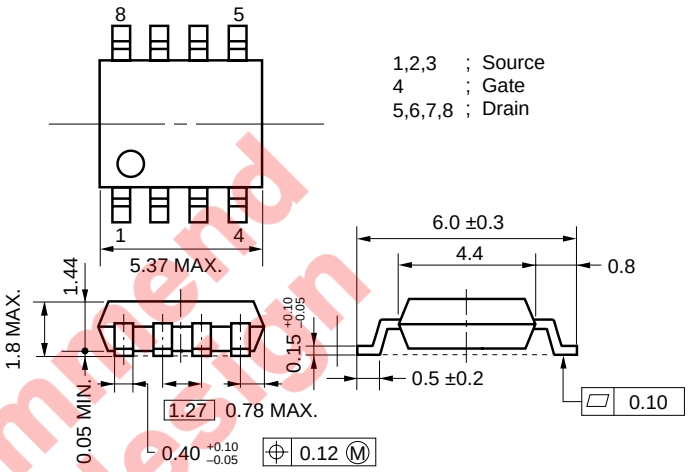
DESCRIPTION

The μPA1717 is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers.

FEATURES

- Low on-state resistance
  $R_{DS(on)1}$ = 33 mΩ MAX. (V_{GS} = –10 V, I_D = –3 A)
  $R_{DS(on)2}$ = 59 mΩ MAX. (V_{GS} = –4.5 V, I_D = –3 A)
- Low C_{iss} : C_{iss} = 830 pF TYP.
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

PACKAGE DRAWING (Unit : mm)



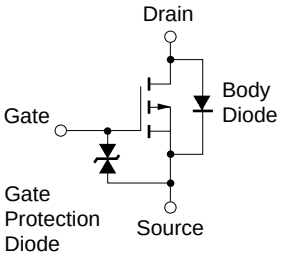
ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1717G	Power SOP8

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, All terminals are connected.)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	–30	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	∓ 25	V
Drain Current (DC)	$I_{D(DC)}$	∓ 6	A
Drain Current (pulse) Note1	$I_{D(pulse)}$	∓ 24	A
Total Power Dissipation (T_A = 25°C) Note2	P_T	2.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C

EQUIVALENT CIRCUIT



Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1 %

2. Mounted on ceramic substrate of 1200 mm^2 x 2.2 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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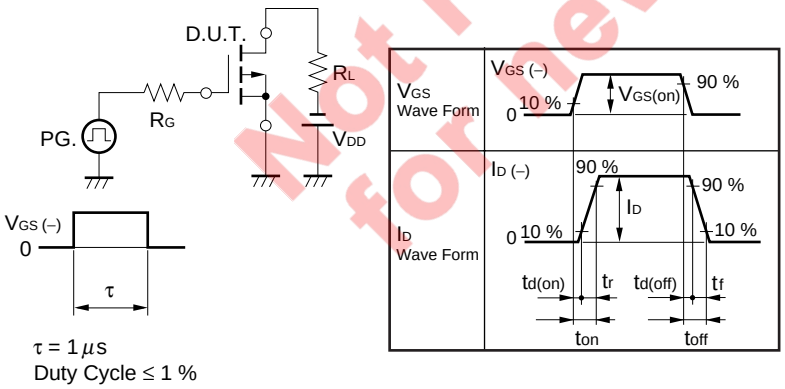
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ELECTRICAL CHARACTERISTICS (T_A = 25 °C, All terminals are connected.)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = –10 V, I_D = –3 A		26	33	mΩ
	$R_{DS(on)2}$	V_{GS} = –4.5 V, I_D = –3 A		44	59	mΩ
Gate to Source Cut-off Voltage	$V_{GS(off)}$	V_{DS} = –10 V, I_D = –1 mA	–1.5	–2.0	–2.5	V
Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = –10 V, I_D = –3 A	3.0	7.5		S
Drain Leakage Current	I_{DSS}	V_{DS} = –30 V, V_{GS} = 0 V			–1	μA
Gate to Source Leakage Current	I_{GSS}	V_{GS} = ∓ 25 V, V_{DS} = 0 V			∓ 10	μA
Input Capacitance	C_{iss}	V_{DS} = –10 V		830		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V		330		pF
Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		130		pF
Turn-on Delay Time	$t_{d(on)}$	I_D = –3 A		15		ns
Rise Time	t_r	$V_{GS(on)}$ = –10 V		120		ns
Turn-off Delay Time	$t_{d(off)}$	V_{DD} = –15 V		70		ns
Fall Time	t_f	R_G = 6 Ω		50		ns
Total Gate Charge	Q_G	I_D = –6 A		15		nC
Gate to Source Charge	Q_{GS}	V_{DD} = –24 V		3		nC
Gate to Drain Charge	Q_{GD}	V_{GS} = –10 V		5		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 6 A, V_{GS} = 0 V		0.82		V
Reverse Recovery Time	t_{rr}	I_F = 6 A, V_{GS} = 0 V		35		ns
Reverse Recovery Charge	Q_{rr}	di/dt = 100 A / μs		15		nC

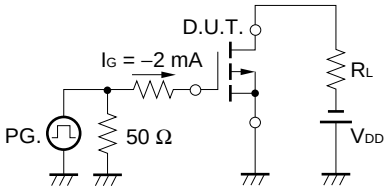
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TEST CIRCUIT 1 SWITCHING TIME



τ = 1 μs
Duty Cycle ≤ 1 %

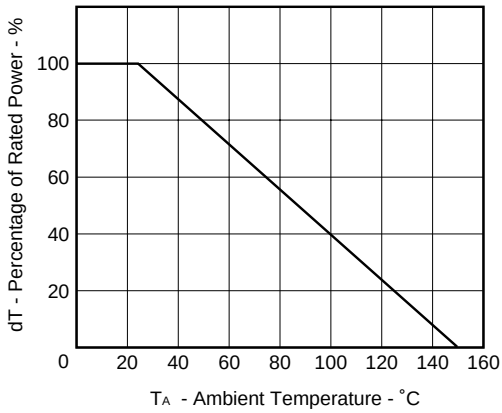
TEST CIRCUIT 2 GATE CHARGE



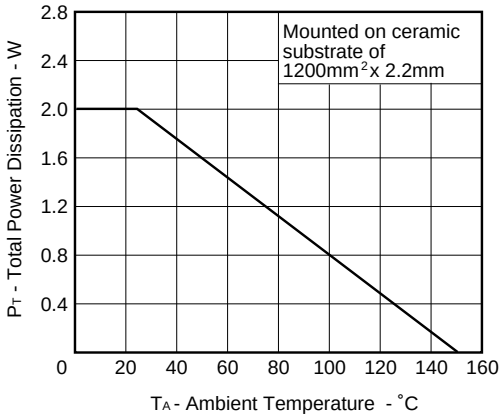
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TYPICAL CHARACTERISTICS (T_A = 25 °C)

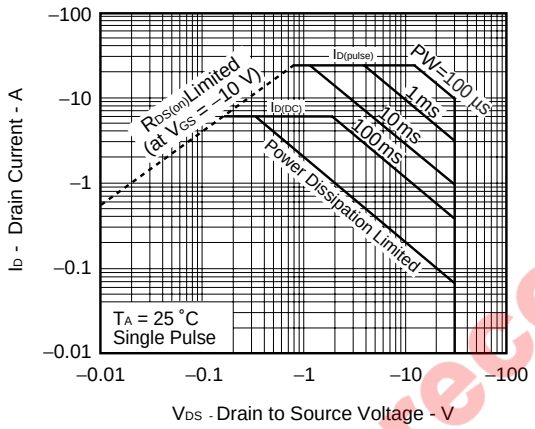
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

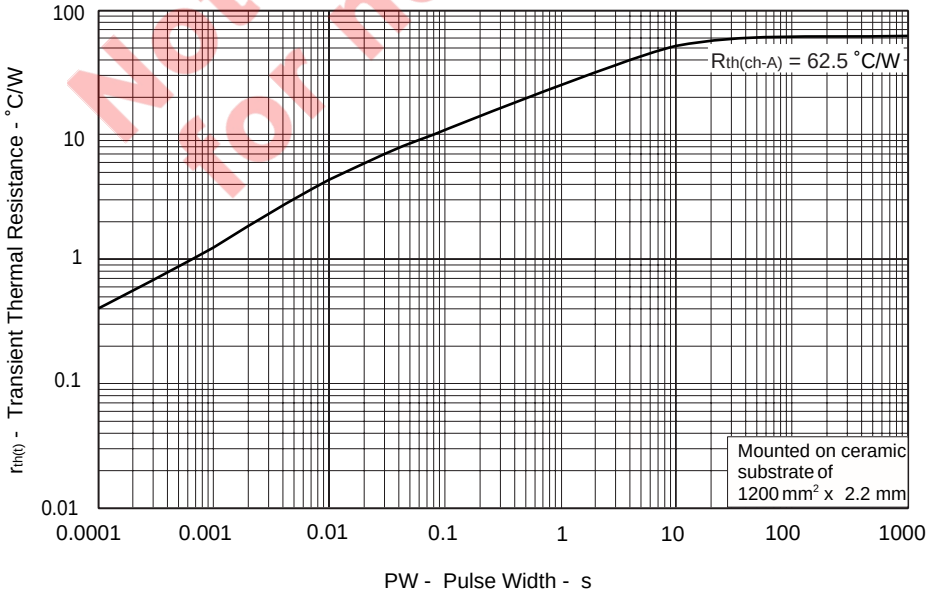


FORWARD BIAS SAFE OPERATING AREA



Remark Mounted on ceramic substrate of 1200 mm^2 x 2.2 mm

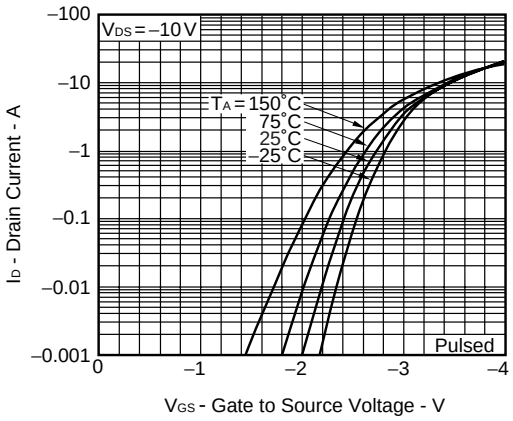
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



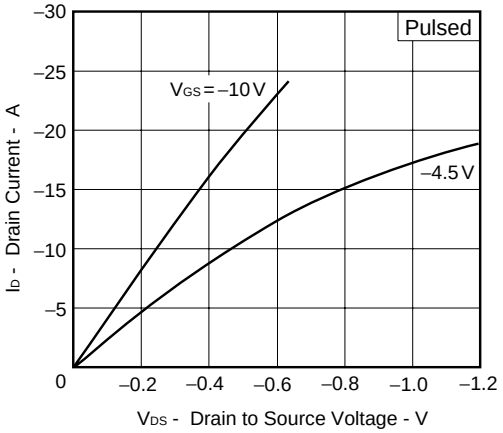
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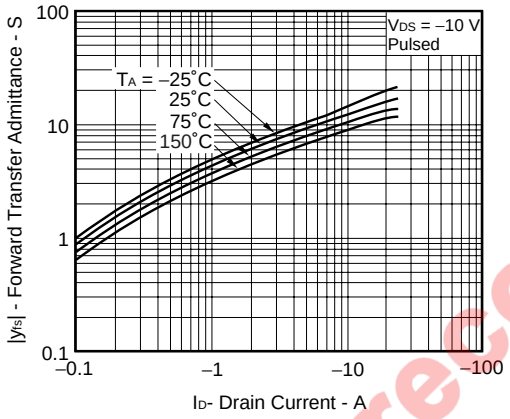
FORWARD TRANSFER CHARACTERISTICS



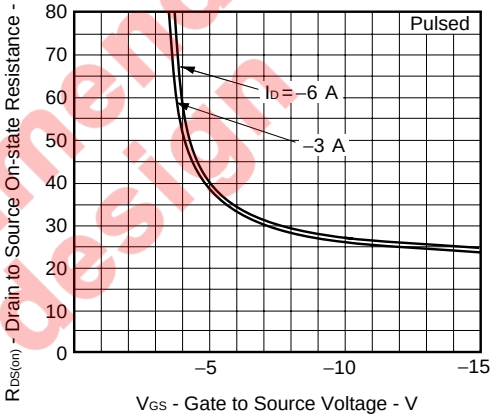
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



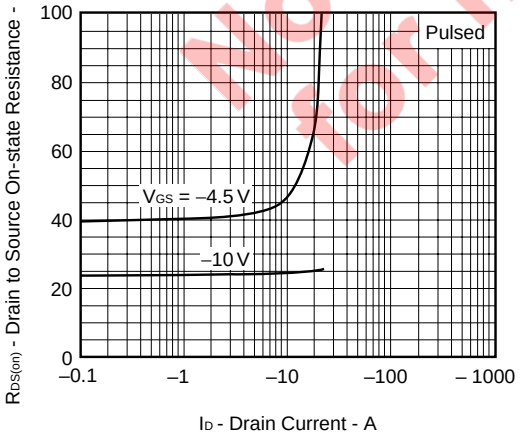
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



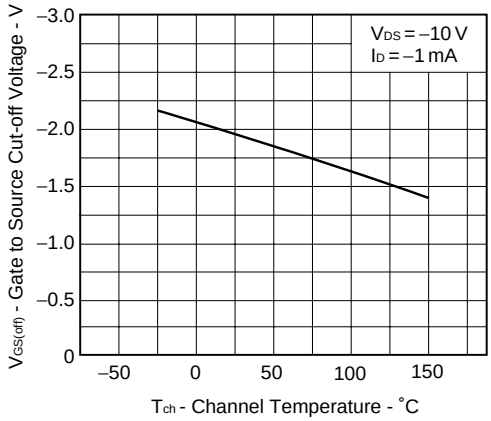
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE
RESISTANCE vs. DRAIN CURRENT



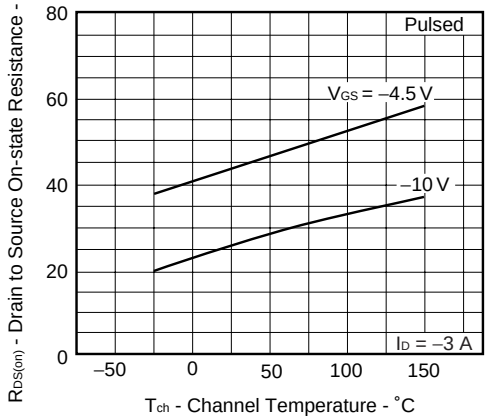
GATE TO SOURCE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



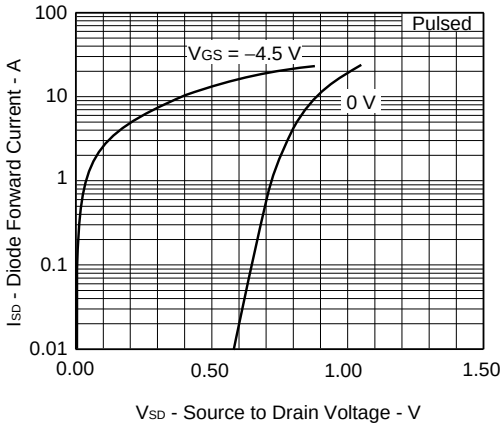
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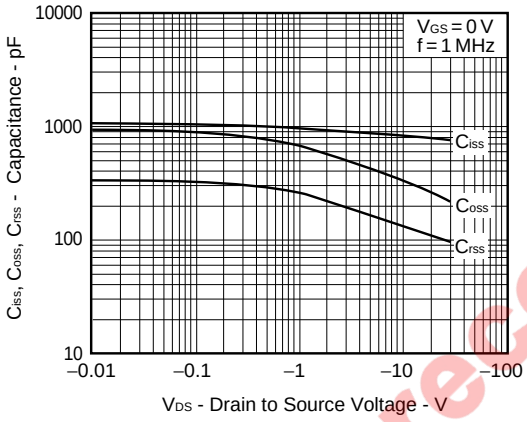
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



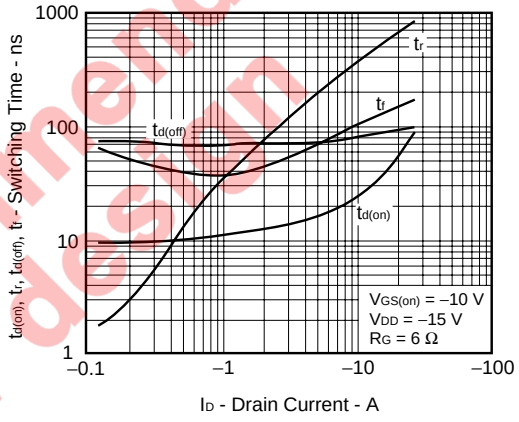
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



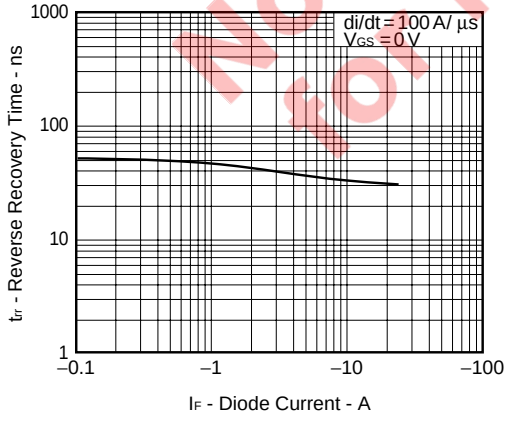
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



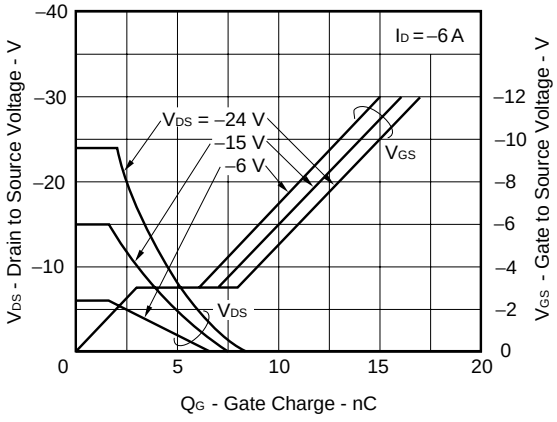
SWITCHING CHARACTERISTICS



REVERSE RECOVERY TIME vs. DIODE CURRENT



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



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